BTA208B series D, E and F

GENERAL DESCRIPTION

Glass passivated high commutation triacs in a plastic envelope suitable for surface mounting, intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

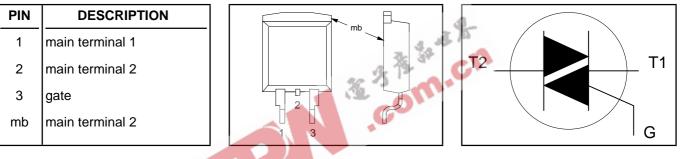
PINNING - SOT404

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BTA208B- BTA208B- BTA208B-	500D 500E 500F	600D 600E 600F	- 800E 800F	
V _{DRM}	Repetitive peak off-state voltages	500	600	800	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	8 65	8 65	8 65	A A

PIN CONFIGURATION

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{DRM}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	-800 800	V
I _{T(RMS)}	RMS on-state current	full sine wave;	-	8			A
I _{TSM}	Non-repetitive peak on-state current	$\begin{array}{l} T_{mb} \leq 102 \ ^{\circ}C \\ \text{full sine wave;} \\ T_{j} = 25 \ ^{\circ}C \ \text{prior to} \\ \text{surge} \end{array}$					
		t = 20 ms t = 16.7 ms	-		65 71		A A
l²t dI _T /dt	I ² t for fusing Repetitive rate of rise of on-state current after triggering	t = 10 ms $I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-		21 100		A²s A/μs
I _{GM} V _{GM}	Peak gate current Peak gate voltage		-		2 5 5		A V
P _{GM} P _{G(AV)}	Peak gate power Average gate power	over any 20 ms	-		5 0.5		Ŵ
T _{stg} T _j	Storage temperature Operating junction temperatureperiod-401500-125			Ĵ, Ĵ			

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 $A/\mu s$.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle minimum footprint, FR4 board		- - 55	2.0 2.4 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.		MAX.		UNIT
		BTA208B-			D	E	F	
I _{GT}	Gate trigger current ²	V _D = 12 V; I _T = 0.1 A T2+ G+ T2+ G-	2 2 2		5 5 5	10 10	25 25	mA mA
IL.	Latching current	T2- G- $V_{D} = 12 V;$ $I_{GT} = 0.1 A$ T2+ G+ T2+ G-	2	S PA	5 6 9	10 12 18	25 30 45	mA mA mA
I _H V _T	Holding current On-state voltage	T2- G- $V_{D} = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$ $I_{T} = 10 \text{ A}$	01	- - 1.3	6 6 1.65	12 12 1.65	30 30 1.65	mA mA V
V _{GT}	Gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}$ $V_{D} = 400 \text{ V}; \text{ I}_{T} = 0.1 \text{ A};$ $T_{1} = 125 \text{ °C}$	- 0.25	0.7 0.4		1.5 -		V V
I _D	Off-state leakage current	$V_D = V_{DRM(max)};$ $T_f = 125 °C$	-	0.1		0.5		mA

DYNAMIC CHARACTERISTICS

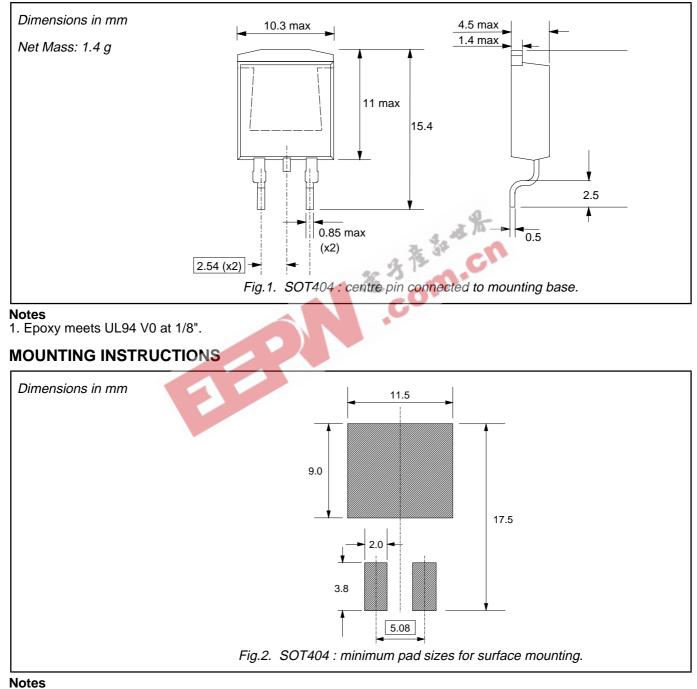
 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.		TYP.	MAX.	UNIT
		BTA208B-	D	E	F			
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)};$ $T_j = 125 °C; exponential waveform; gate open circuit$	10	20	50	-	-	V/µs
dl _{com} /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 \text{ °C};$ $I_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20v/\mu s; \text{ gate}$ open circuit	1.8	2.5	3.5	-	-	A/ms
t _{gt}	Gate controlled turn-on time	$I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu\text{s}$	-	-	-	2	-	μs

² Device does not trigger in the T2-, G+ quadrant.

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MECHANICAL DATA



1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
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